

## **KBP005 THRU KBP10**

SINGLE-PHASE SILICON BRIDGE Reverse Voltage - 50 to 1000 Volts Forward Current - 2.0 Amperes

## Features

- Surge overload rating 50 amperes peak
- Ideal for printed circuit board
- Plastic material has Underwriters Laboratory Flammability Classification 94V-0
- Mounting Position: Any
- Lead: Silver plated copper lead

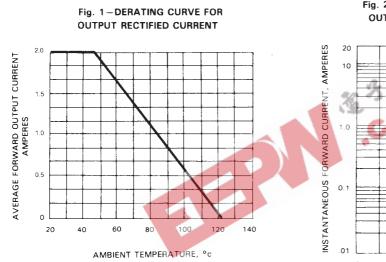
<u>RS-2</u> DIMENSIONS inches DIM Note M in. Max. Min. Max 0.504 12.8 А В 0.75 19.0 С 0.693 17.6 D 0.25 6.4 Е 0.125 3.2 F 0.15 3.8 G 0.32 Typ. 0.8 Typ.

## **Maximum Ratings and Electrical Characteristics**

Ratings at 25°C ambient temperature unless otherwise specified. Resistive or inductive load, 60Hz. For capacitive load, derate current by 20%.

	Symbols	KBP005	KBP01	KBP02	KBP04	KBP06	KBP08	KBP10	Units
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	Volts
Maximum RMS bridge input voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	Volts
Maximum average forward rectified output current at $T_{\rm A}{=}50{\rm ^{\circ}C}$	I <sub>(AV)</sub>	2.0							Amps
Peak forward surge current, 8.3mS single half sine-wave superimposed on rated load	I	50.0						Amps	
Maximum forward Voltage drop per bridge element at 1.0A peak	V <sub>F</sub>	1.0							Volt
Maximum DC reverse current at rated DC blocking voltage per element	I <sub>R</sub>	10.0							μA
$\begin{array}{ll} \mbox{Maximum DC reverse current at rated} \\ \mbox{DC blocking voltage per element} & $T_{\rm A}$=100 \ensuremath{^\circ}{\rm C}$ \end{array}$	I <sub>R</sub>	1.0							mA
Operating temperature range	T	-55 to +125							°C
Storage temperature range	T <sub>stg</sub>	-55 to +150							°C

## **RATINGS AND CHARACTERISTIC CURVES**



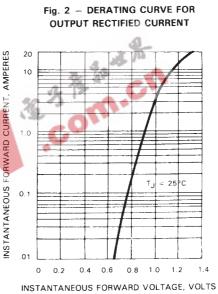


Fig. 3 — TYPICAL FORWARD CHARACTERISTICS

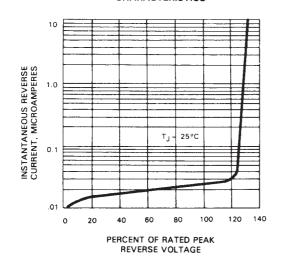


Fig. 4 - MAXIMUM FORWARD SURGE CURRENT

